

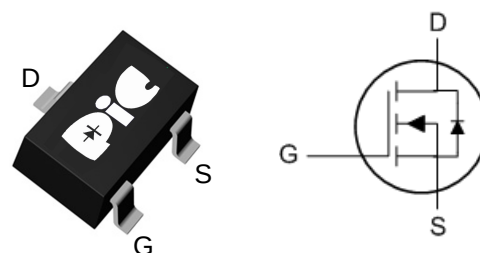
➤ General Description

This PAN3036R N-Channel enhancement mode power field effect transistor is the high density trench technology and this advanced technology can provide excellent $R_{DS(ON)}$ performance and efficiency for power switching and load switching application., this device also comply with the RoHS and Green Product requirement with full function reliability approved.

➤ Feature

- Super high density cell design for extremely low $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability
- SOT-323 package design

➤ SOT-323



➤ Application

- Portable Equipment
- Battery Powered System
- Net Working System

➤ Absolute Maximum Ratings

Parameter		Symbol	Maximum Ratings	Unit
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	± 12	V
Continuous Drain Current	$T_A=25^\circ C$	I_D	1.8	A
	$T_A=70^\circ C$		1.4	
Pulsed Drain Current		I_{DM}	5.4	
Maximum Power Dissipation	$T_A=25^\circ C$	P_D	0.34	W
	$T_A=70^\circ C$		0.22	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 150	$^\circ C$
Thermal Resistance-Junction to Ambient*		$R_{\theta JA}$	367	$^\circ C/W$

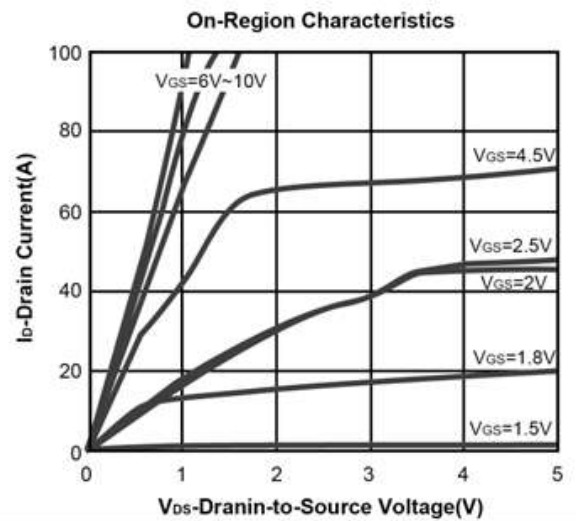
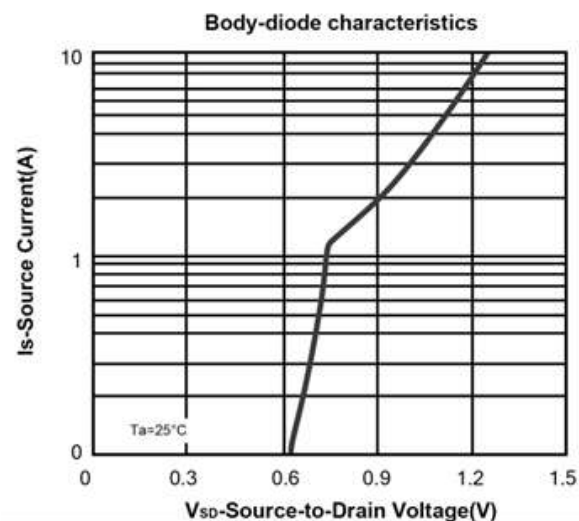
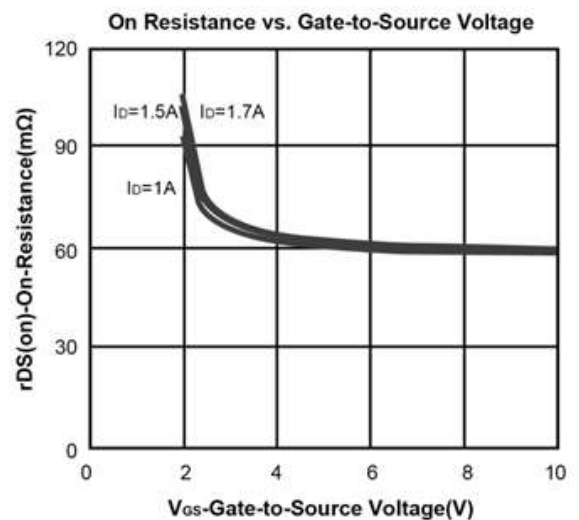
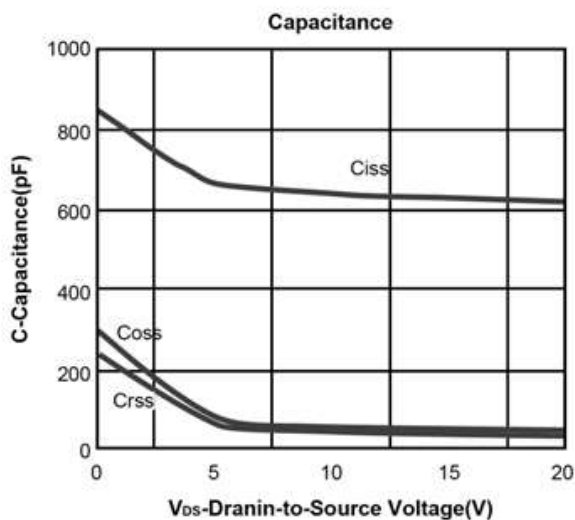
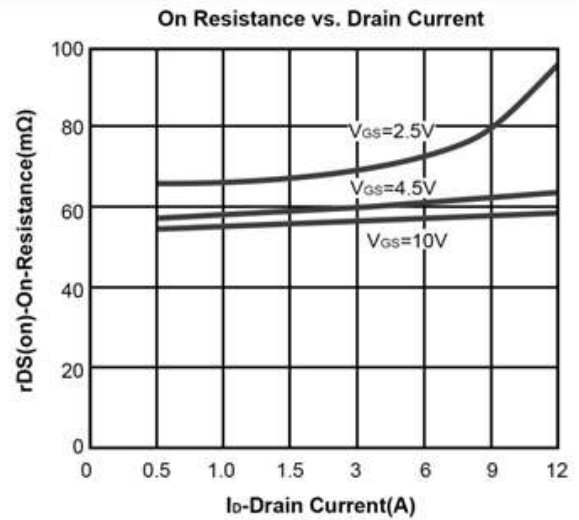
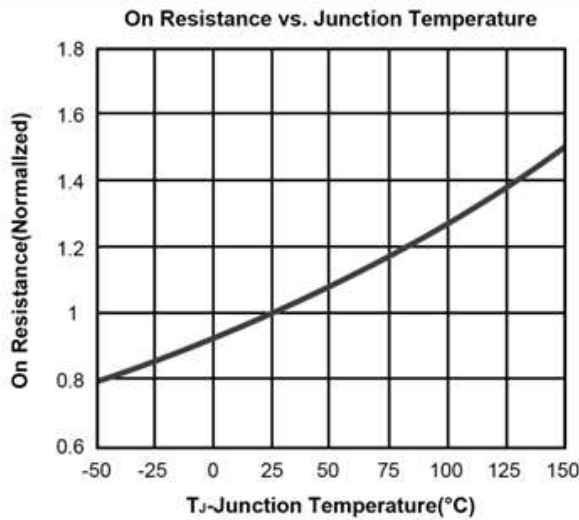
*The device mounted on 1in2 FR4 board with 2 oz copper

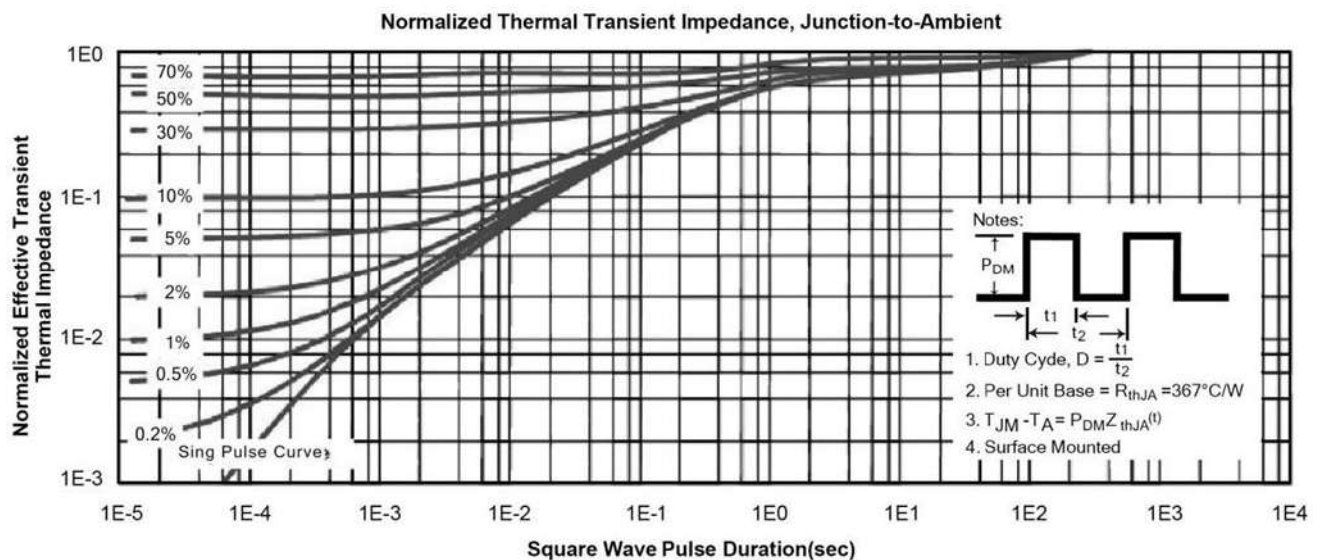
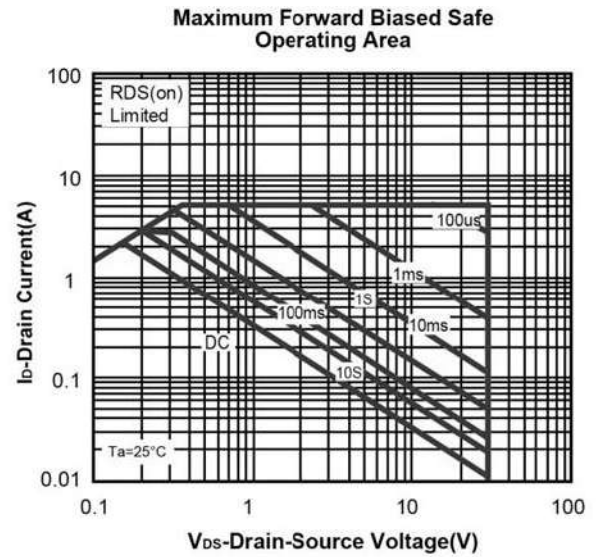
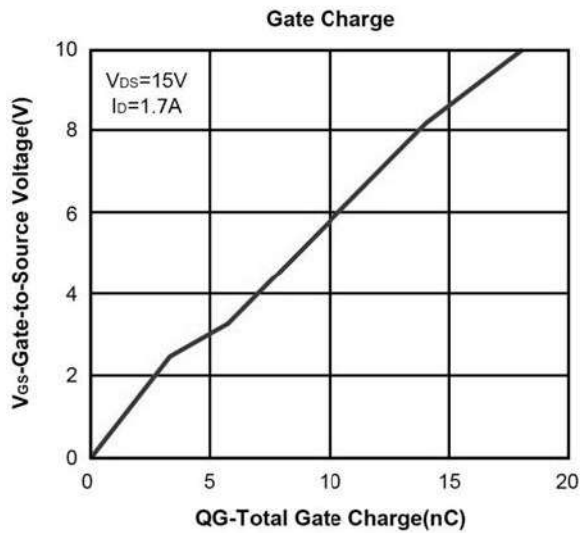
➤ Electrical Characteristics ($T_A=25^\circ C$ Unless otherwise noted)

Symbol	Parameter	Limit	Min	Typ	Max	Unit
STATIC PARAMETERS						
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V$, $I_D=250\mu A$	30			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$, $I_D=250\mu A$	0.7		1.4	
I_{GSS}	Gate-Body Leakage Current	$V_{DS}=0V$, $V_{GS}=\pm 12V$			± 100	nA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=30V$, $V_{GS}=0V$			1	μA
$R_{DS(ON)}$	Drain-Source On-Resistance ^a	$V_{GS}=10V$, $I_D=1.7A$		58	70	$m\Omega$
		$V_{GS}=4.5V$, $I_D=1.5A$		61	75	
		$V_{GS}=2.5V$, $I_D=1A$		69	85	
V_{SD}	Diode Forward Voltage	$I_S=1.25A$, $V_{GS}=0V$		0.8	1.2	V
DYNAMIC PARAMETERS						
Q_g	Total Gate Charge	$V_{DS}=15V$, $V_{GS}=10V$, $I_D=1.7A$		17		nC
Q_{gs}	Gate-Source Charge			3.6		
Q_{gd}	Gate-Drain Charge			2.3		
C_{iss}	Input Capacitance	$V_{DS}=15V$, $V_{GS}=0V$, $f=1MHz$		627		pF
C_{oss}	Output Capacitance			48		
C_{rss}	Reverse Transfer Capacitance			40		
$t_{d(on)}$	Turn-On Delay Time	$V_{DS}=15V$, $V_{GS}=10V$, $I_D=1.7A$, $R_G=6\Omega$		7.4		ns
t_r	Rise Time			31.5		
$t_{d(off)}$	Turn-Off Delay Time			25.1		
t_f	Fall Time			10.7		

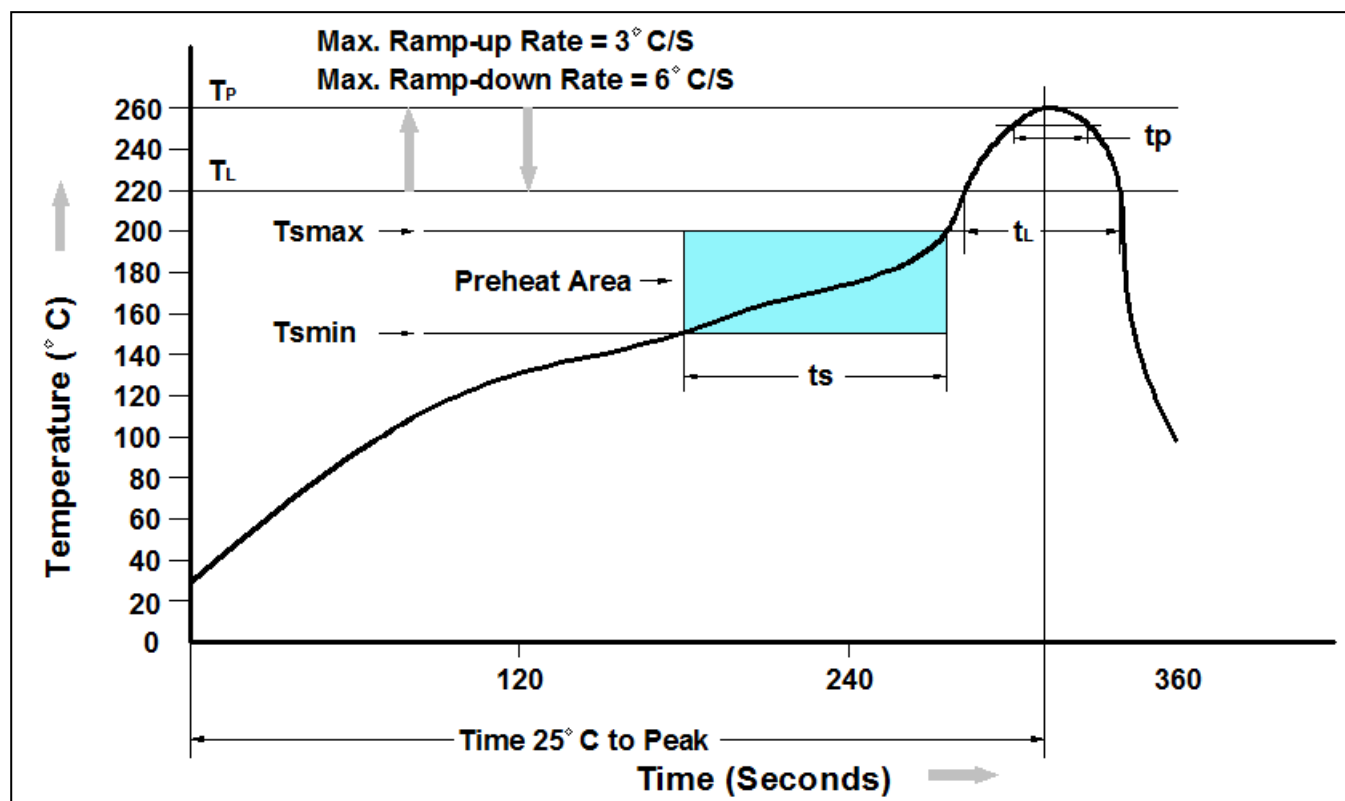
Notes: a. Pulse test; pulse width $\leq 380\mu s$, duty cycle $\leq 2\%$

➤ Typical Characteristics





➤ Recommand IR Reflow Soldering Thermal Profile

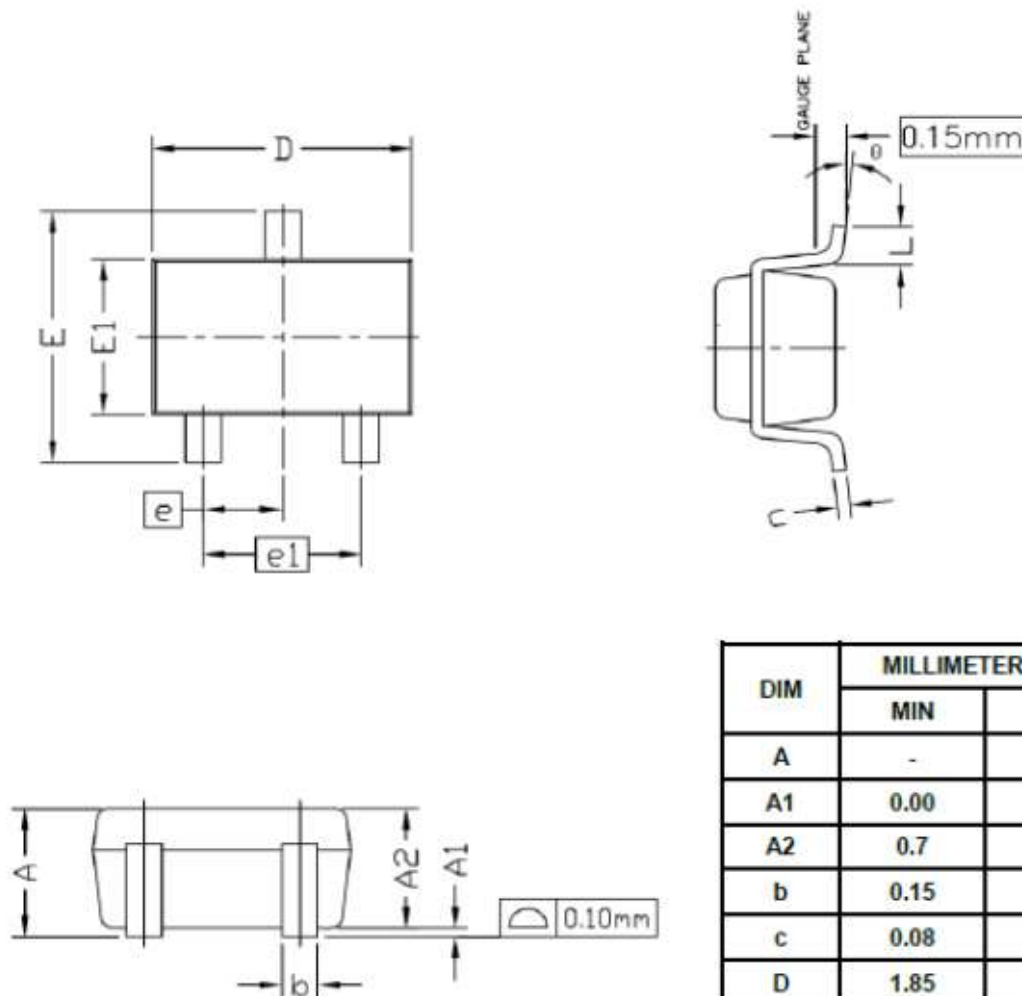


Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T_{Smin})	150°C
Temperature Max. (T_{Smax})	200°C
Time (t_S) from (T_{Smin} to T_{Smax})	60-120 seconds
Average Ramp-up Rate (t_L to t_P)	3°C/second max.
Liquidous Temperature (T_L)	217°C
Time (t_L) Maintained Above (T_L)	60 – 150 seconds
Peak Temperature	260°C +0°C / -5°C
Time (t_P) within 5°C of actual Peak Temperature	30 seconds
Ramp-down Rate (T_P to T_L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.

➤ Ordering Information

Part Number	Description	Quantity
PAN3036R	SOT-323 Reel	3000 pcs

➤ Package Information (SOT-323)



DIM	MILLIMETERS (mm)	
	MIN	MAX
A	-	1.10
A1	0.00	0.10
A2	0.7	1.00
b	0.15	0.30
c	0.08	0.22
D	1.85	2.15
E	1.80	2.40
e	0.65 BSC	
e1	1.30 BSC	
E1	1.1	1.4
L	0.10	-
θ	0°	8°

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